

Title (en)
SURFACE ELECTRON DISPLAY DEVICE AND FABRICATION PROCESS

Title (de)
ELEKTRONENEMITTIERENDE ANZEIGEVORRICHTUNG DES OBERFLACHEN-TYPS UND VERFAHREN ZUR HERSTELLUNG

Title (fr)
DISPOSITIF D'AFFICHAGE ELECTRONIQUE A BALAYAGE DE SURFACE ET PROCEDE DE FABRICATION

Publication
EP 0948800 A2 19991013 (EN)

Application
EP 97954214 A 19971230

Priority

- US 9723718 W 19971230
- US 3378896 P 19961230
- US 3378796 P 19961230
- US 96448397 A 19971105
- US 96498797 A 19971105

Abstract (en)
[origin: WO9832145A2] A device useful as a display element has an electron emitter and an anode disposed to receive electrons emitted from the emitter. The anode has surface portions differing in resistivity, providing an electron sink portion at the surface portion of lowest resistivity. A preferred embodiment has a lateral field-emission electron emitter and has an anode formed by processes specially adapted to provide anode portions of differing resistivity, including the electron sink portion. The electron sink portion is preferably disposed at a position laterally spaced apart from the emitting tip of the device's electron emitter. In a particularly preferred fabrication process, the anode is formed by depositing a base layer, depositing and patterning an etch-stop layer with an opening to define the electron-sink portion, forming an opening by etching overlying layers down to the etch-stop layer, and heating the base layer and etch-stop layer to form an anode surface that includes both an integral electron-sink portion and a cathodoluminescent phosphor for emitting light. The fabrication process provides for fabricating a plurality of display element devices to make a flat panel display.

IPC 1-7
H01J 9/00; **H01J 29/00**

IPC 8 full level
C09K 11/54 (2006.01); **C09K 11/67** (2006.01); **H01J 1/304** (2006.01); **H01J 1/36** (2006.01); **H01J 3/02** (2006.01); **H01J 9/02** (2006.01); **H01J 9/14** (2006.01); **H01J 9/22** (2006.01); **H01J 29/18** (2006.01); **H01J 29/20** (2006.01); **H01J 31/12** (2006.01)

CPC (source: EP KR)
H01J 3/022 (2013.01 - EP); **H01J 9/025** (2013.01 - EP); **H01J 19/24** (2013.01 - KR)

Citation (search report)
See references of WO 9832145A2

Designated contracting state (EPC)
DE FR GB NL

DOCDB simple family (publication)
WO 9832145 A2 19980723; **WO 9832145 A3 19981119**; AU 5805298 A 19980807; CA 2274664 A1 19980723; EP 0948800 A2 19991013; JP 2001525105 A 20011204; KR 20000069815 A 20001125

DOCDB simple family (application)
US 9723718 W 19971230; AU 5805298 A 19971230; CA 2274664 A 19971230; EP 97954214 A 19971230; JP 53437898 A 19971230; KR 19997005971 A 19990630